IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Haupt et al. Docket No.: QIM 2003 P 51718 US

Serial No.: 10/766,053 Art Unit: 2892

Filed: January 28, 2004 Examiner: Tran, Thanh Y.

For: Method for N+ doping of Amorphous Silicon and Polysilicon Electrodes in

Deep Trenches

Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

RESPONSE UNDER 37 C.F.R. § 1.116

Dear Sir:

Applicant respectfully submits the following remarks in response to the final Office Action dated October 27, 2009. Applicant respectfully requests that these remarks be entered pursuant to the provisions of 37 C.F.R. § 1.116, and respectfully requests reconsideration of the claims.

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